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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Bong-Cheol Kim
Serial No. : 10/089,479 Examiner: Nhu, David
Filed : March 28, 2002 Group Art Unit: 2812
For : APPARATUS AND METHOD FOR FORMING SINGLE CRYSTALLINE NITRIDE SUBSTRATE USING HYDRIDE VAPOR PHASE EPITAXY AND LASER BEAM

LETTER

I hereby certify that this paper is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231

June 22, 2003

Date of Deposit

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Date of Signature

Commissioner for Patents
P.O. BOX 1450
Alexandria, VA 22313-1450

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Sir:

Applicant respectfully requests that the references listed in the PTO 1449 of the Supplemental Information Disclose Statement filed on June 2, 2003, for the above-identified application be disregarded and not made of record as the statement was filed in error.

Respectfully submitted,

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